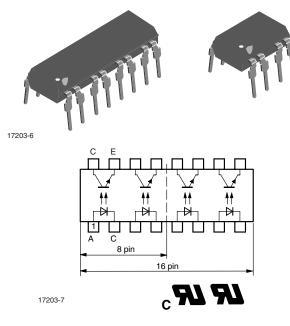


**Vishay Semiconductors** 

# **Optocoupler, Phototransistor Output**



### DESCRIPTION

In the K827PH, K847PH parts each channel consist of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 8 pin (dual); 16 pin (quad) plastic dual inline package.

ORDER INFORMATION					
PART	REMARKS				
K827PH	CTR 50 % to 600 %, DIP-8				
K847PH	CTR 50 % to 600 %, DIP-16				

#### Note

K827PH and K847PH are marked as K827P and K847P respectively.

<b>ABSOLUTE MAXIMUM RATINGS</b> <sup>(1)</sup> ( $T_{amb} = 25 \degree C$ , unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT							
Reverse voltage		V <sub>R</sub>	6	V			
Forward current		I <sub>F</sub>	60	mA			
Forward surge current	t <sub>P</sub> ≤ 10 µs	I <sub>FSM</sub>	1.5	A			
Power dissipation		P <sub>diss</sub>	100	mW			
Junction temperature		Tj	125	°C			
OUTPUT							
Collector emitter voltage		V <sub>CEO</sub>	70	V			
Emitter collector voltage		V <sub>ECO</sub>	7	V			
Collector current		Ι <sub>C</sub>	50	mA			
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I <sub>CM</sub>	100	mA			
Power dissipation		P <sub>diss</sub>	150	mW			
Junction temperature		Tj	125	°C			

### **FEATURES**

- DC isolation test voltage 5000 V<sub>RMS</sub>
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

### **APPLICATIONS**

- Programmable logic controllers
- Modems
- Answering machines
- General applications

### **AGENCY APPROVALS**

- UL1577, file no. E57244 system code H, double protection
- cUL tested to CSA 22.2 bulletin 5A, UL1577, file no. E52744





COMPLIANT



# K827PH, K847PH



### Vishay Semiconductors Optocoupler, Phototransistor Output

<b>ABSOLUTE MAXIMUM RATINGS</b> <sup>(1)</sup> ( $T_{amb} = 25 \degree C$ , unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
COUPLER							
AC isolation test voltage (RMS)	t = 1 min	V <sub>ISO</sub>	5000	V <sub>RMS</sub>			
Total power dissipation		P <sub>tot</sub>	250	mW			
Operating ambient temperature range		T <sub>amb</sub>	- 40 to + 100	°C			
Storage temperature range		T <sub>stg</sub>	- 55 to + 125	°C			
Soldering temperature <sup>(2)</sup>	2 mm from case, t $\leq$ 10 s	T <sub>sld</sub>	260	°C			

#### Notes

(1) Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

<sup>(2)</sup> Refer to wave profile for soldering conditions for through hole devices.

<b>ELECTRICAL CHARACTERISTICS</b> <sup>(1)</sup> ( $T_{amb} = 25 \text{ °C}$ , unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT								
Forward voltage	I <sub>F</sub> = 50 mA	V <sub>F</sub>		1.25	1.6	V		
Junction capacitance	V <sub>R</sub> = 0 V, f = 1 MHz	Cj		50		pF		
OUTPUT								
Collector emitter voltage	I <sub>C</sub> = 100 μA	V <sub>CEO</sub>	70			V		
Emitter collector voltage	I <sub>E</sub> = 100 μA	V <sub>ECO</sub>	7			V		
Collector dark current	$V_{CE} = 20 \text{ V}, I_F = 0, E = 0$	I <sub>CEO</sub>			100	nA		
COUPLER								
Collector emitter saturation voltage	$I_{\rm F} = 10$ mA, $I_{\rm C} = 1$ mA	V <sub>CEsat</sub>			0.3	V		
Cut-off frequency	$I_{F} = 10 \text{ mA}, V_{CE} = 5 \text{ V}, \\ R_{L} = 100 \ \Omega$	f <sub>c</sub>		100		kHz		
Coupling capacitance	f = 1 MHz	C <sub>k</sub>		0.3		pF		

#### Note

<sup>(1)</sup> Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I <sub>C</sub> /I <sub>F</sub>	$V_{CE}$ = 5 V, I <sub>F</sub> = 5 mA	K827PH	CTR	50		600	%
		K847PH	CTR	50		600	%



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SWITCHING CHARACTERISTICS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Delay time	$\label{eq:VS} \begin{array}{l} V_{S} = 5 \; V, \; I_{C} = 2 \; mA, \; R_{L} = 100 \; \Omega \\ (\text{see figure 1}) \end{array}$	t <sub>d</sub>		3		μs	
Rise time	$V_S$ = 5 V, I <sub>C</sub> = 2 mA, R <sub>L</sub> = 100 $\Omega$ (see figure 1)	t <sub>r</sub>		3		μs	
Fall time	$\label{eq:VS} \begin{array}{l} V_{S} = 5 \; V, \; I_{C} = 2 \; mA, \; R_{L} = 100 \; \Omega \\ (\text{see figure 1}) \end{array}$	t <sub>f</sub>		4.7		μs	
Storage time	$V_S$ = 5 V, I <sub>C</sub> = 2 mA, R <sub>L</sub> = 100 $\Omega$ (see figure 1)	t <sub>s</sub>		0.3		μs	
Turn-on time	$V_S$ = 5 V, I <sub>C</sub> = 2 mA, R <sub>L</sub> = 100 $\Omega$ (see figure 1)	t <sub>on</sub>		6		μs	
Turn-off time	$V_{S}$ = 5 V, I <sub>C</sub> = 2 mA, R <sub>L</sub> = 100 $\Omega$ (see figure 1)	t <sub>off</sub>		5		μs	
Turn-on time	$V_S$ = 5 V, $I_F$ = 10 mA, $R_L$ = 1 k $\Omega$ (see figure 2)	t <sub>on</sub>		9		μs	
Turn-off time	$V_S$ = 5 V, $I_F$ = 10 mA, $R_L$ = 1 k $\Omega$ (see figure 2)	t <sub>off</sub>		18		μs	

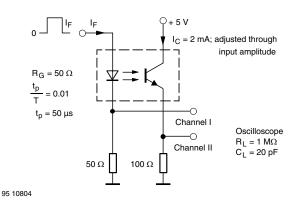


Fig. 1 - Test Circuit, Non-Saturated Operation

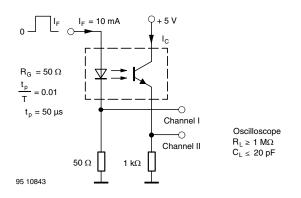


Fig. 2 - Test Circuit, Saturated Operation

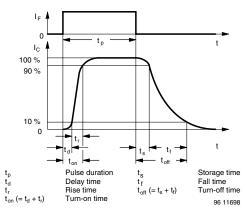


Fig. 3 - Switching Times

## K827PH, K847PH

Vishay Semiconductors Optocoupler, Phototransistor Output



TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

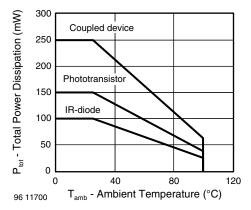


Fig. 4 - Total Power Dissipation vs. Ambient Temperature

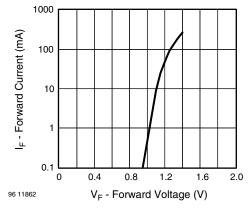


Fig. 5 - Forward Current vs. Forward Voltage

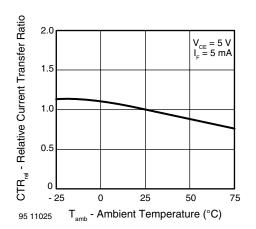


Fig. 6 - Relative Current Transfer Ratio vs. Ambient Temperature

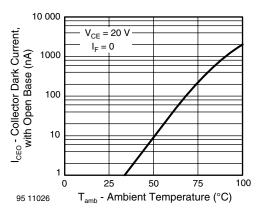
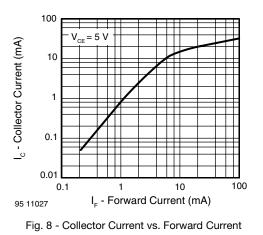
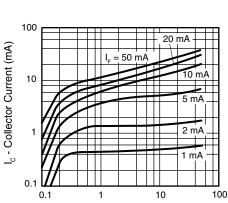


Fig. 7 - Collector Dark Current vs. Ambient Temperature





95 10985 V<sub>CE</sub> - Collector Emitter Voltage (V)

Fig. 9 - Collector Current vs. Collector Emitter Voltage



## Optocoupler, Phototransistor Output Vishay Semiconductors

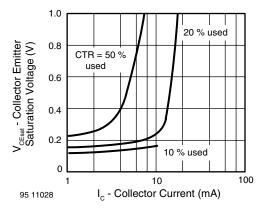


Fig. 10 - Collector Emitter Saturation Voltage vs. Collector Current

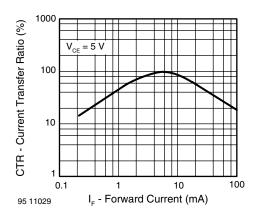


Fig. 11 - Current Transfer Ratio vs. Forward Current

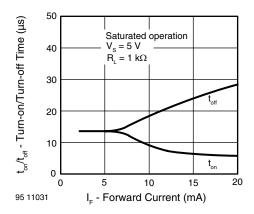


Fig. 12 - Turn-on/Turn-off Time vs. Forward Current

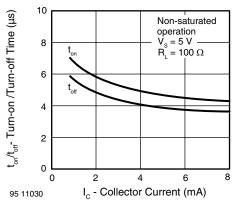
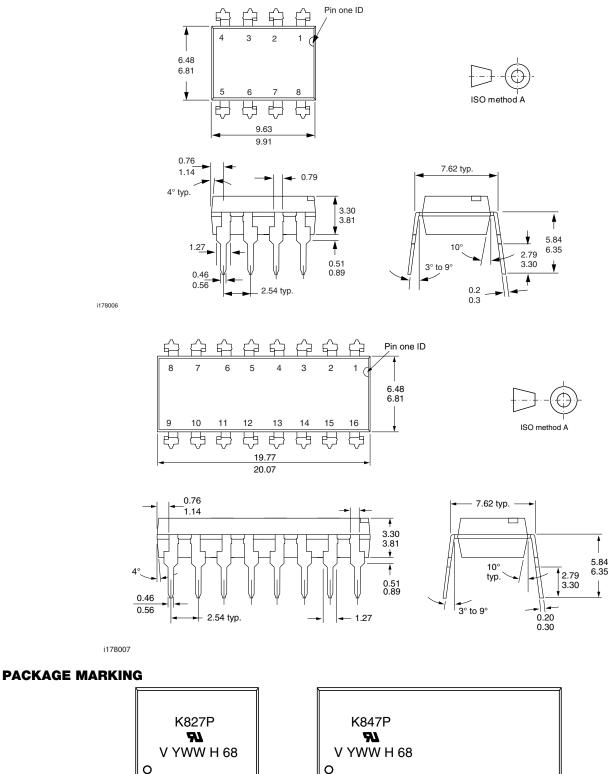


Fig. 13 - Turn-on/off Time vs. Collector Current

Vishay Semiconductors Optocoupler, Phototransistor Output



### **PACKAGE DIMENSIONS** in millimeters





Vishay

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